Technical Data
Data Sheet N1416, Rev. -

Green Products

ST1060C/STB1060C/STD1060C SCHOTTKY RECTIFIER

Applications:

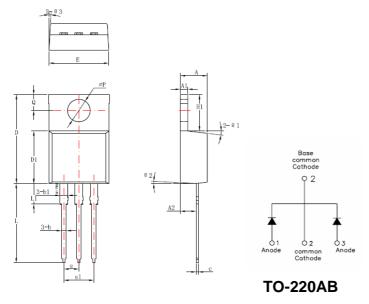
- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Features:

- 150 °C T_J operation
- Center tap configuration
- Ultralow forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



Mechanical Dimensions: In Inches / mm



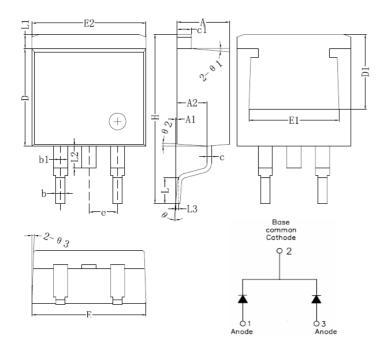
	Difficusions in			
Symbol	millimeters Min Typical Max			
	Min	Min Typical		
Α	4.42	4.57	4.72	
A1	1.17	1.27	1.37	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1		1.27		
С	0.36	0.38	0.61	
D	14.94	15.24	15.54	
D1	8.85	9.00	9.15	
E	10.01	10.16	10.31	
e		2.54		
e1		5.06		
H1	6.04	6.24	6.44	
L	12.7	13.56	13.78	
L1		3.5		
ΦР	3.74	3.84	4.04	
Q	2.54	2.74	2.94	
Θ1		7°		
Θ2		3°		
Θ3		4°		
-	•			

Dimensions in

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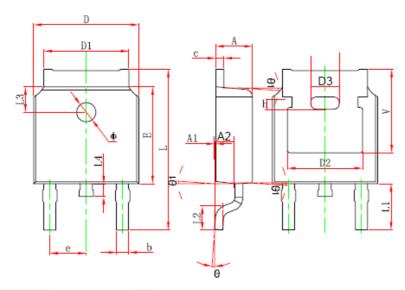
0	Dimensions in				
Symbol	millimeters				
	Min.	Typical	Max.		
Α	4.55	4.70	4.85		
A 1	0	0.10	0.25		
A2	2.59	2.69	2.89		
b	0.71	0.81	0.96		
b1		1.27			
С	0.36	0.38	0.61		
c1	1.17	1.27	1.37		
D	8.55	8.70	8.85		
D1	6.40				
E	10.01	10.16	10.31		
E1	7.6				
E2	9.98	10.08	10.18		
е		2.54			
Н	14.6	15.1	15.6		
L	2.00	2.30	2.70		
L1	1.17	1.27	1.40		
L2			2.20		
L3		0.25BSC			
е	0	-	8°		
e1		5°			
e2		4°			
e3		4°			

 D^2PAK

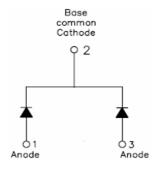
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Symbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
Α	2.200	2.380	0.087	0.094	
A1	0.000	0.100	0.000	0.004	
b	0.710	0.810	0.028	0.032	
С	0.460	0.560	0.018	0.022	
D	6.500	6.700	0.256	0.264	
D1	5.130	5.460	0.202	0.215	
D2	4.830	REF.	0.190	REF.	
E	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.900	2.900 REF.		0.114 REF.	
L2	1.400	1.700	0.055	0.067	
L3	1.600	REF.	0.063 REF.		
L4	0.600	1.000	0.024	0.039	
Φ	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
A2	0.910	1.110	0.036	0.044	
V	5.350 REF.		0.211	REF.	
D3	1.778REF.		0.070	REF.	
h	0.762REF.		0.030	REF.	
θ1	7°		7'°		



DPAK

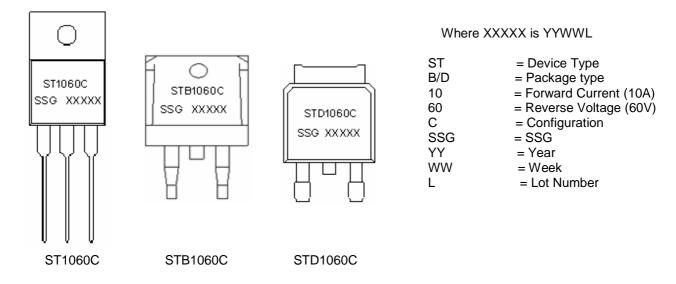
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Marking Diagram:



Cautions: Molding resin

Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
ST1060C	TO-220AB(Pb-Free)	50pcs / tube
STB1060C	D² PAK(Pb-Free)	800pcs / reel
STD1060C	DPAK(Pb-Free)	2500pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	60	V
Average Forward Current	I _{F(AV)}	50% duty cycle @T _C =100℃, rectangular wave form	10	А
Peak One Cycle Non-Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	100	A

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Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Forward Voltage Drop	V_{F1}	@ 5A, Pulse, T _J = 25 °C	0.70	V
(per leg)*	V_{F2}	@ 5A, Pulse, T _J = 125 °C	0.60	V
Reverse Current (per leg)*	I _{R1}	$@V_R = \text{rated } V_R$ $T_J = 25 ^{\circ}\text{C}$	0.7	mA
	I _{R2}	$@V_R = \text{rated } V_R$ $T_J = 125 ^{\circ}\text{C}$	25	mA
Junction Capacitance (per leg)	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	300	pF
Voltage Rate of Change	dv/dt	-	10,000	V/μs

^{*} Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	ST1060C	STB1060C	STD1060C	Units
Junction Temperature	TJ		-55 to +150		°C
Storage Temperature	T _{stg}	-55 to +150			°C
Maximum Thermal Resistance Junction to Case(per leg)*	$R_{ heta JC}$	3.5	3.5	3	°C/W
Approximate Weight	wt	2	1.85	0.39	g
Case Style		TO-220AB/ D ² PAK/ DPAK			

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